

PC725V

High Sensitivity, High Collector-emitter Voltage Type Photocoupler

- ※ Lead forming type (W type) and taping reel type (P type) are also available. (PC725W/PC725VP)
- ※ TÜV (VDE0884) approved type as an option is also available.

■ Features

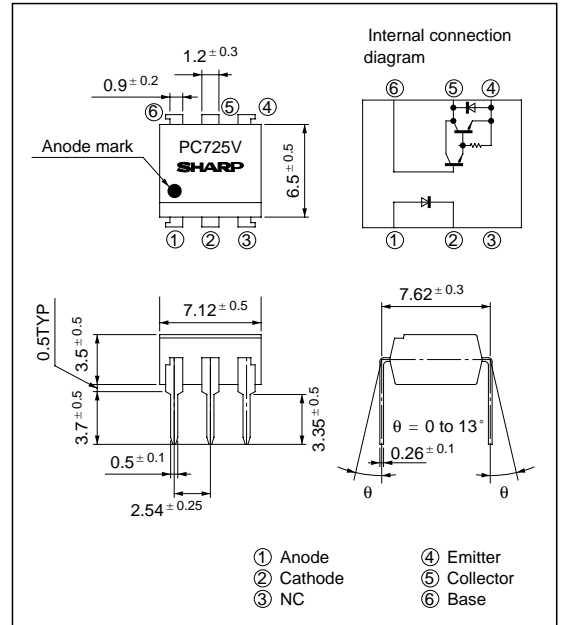
1. High collector-emitter voltage
(V_{CEO} : 300V)
2. High current transfer ratio
(CTR : MIN. 1 000% at $I_F = 1\text{mA}$, $V_{CE} = 2\text{V}$)
3. High isolation voltage between input and output
(V_{ISO} : 5 000V_{rms})
4. Low collector dark current
(I_{CEO} : MAX. 10^{-6}A at $V_{CE} = 200\text{V}$)
5. Recognized by UL, file No. E64380

■ Applications

1. Telephone sets, telephone exchangers
2. Power apparatus switchboards
3. Numerical control machines
4. DC-DC SSRs, DC motor controllers

■ Outline Dimensions

(Unit : mm)



■ Absolute Maximum Ratings

(T_a = 25°C)

	Parameter	Symbol	Rating	Unit
Input	Forward voltage	I_F	50	mA
	^{*1} Peak forward voltage	I_{FM}	1	A
	Reverse current	V_R	6	V
	Power dissipation	P	70	mW
Output	Collector-emitter voltage	V_{CEO}	300	V
	Collector-base voltage	V_{CBO}	300	V
	Emitter-base voltage	V_{EBO}	6	V
	Collector current	I_C	150	mA
	Collector current (reverse)	$-I_C$	10	mA
	Collector power dissipation	P_C	300	mW
	Total power dissipation	P_{tot}	350	mW
	^{*2} Isolation voltage	V_{iso}	5 000	V _{rms}
	Operating temperature	T_{opr}	- 25 to + 100	°C
	Storage temperature	T_{stg}	- 40 to + 125	°C
	^{*3} Soldering temperature	T_{sol}	260	°C

*1 Pulse width ≤ 100μs, Duty ratio : 0.001

*2 40 to 60% RH, AC for 1 minute

*3 For 10 seconds

■ Electro-optical Characteristics

(T_a = 25°C)

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit		
Input	Forward voltage	V _F	I _F = 10mA	-	1.2	1.4	V		
	Peak forward voltage	V _{FM}	I _{FM} = 0.5A	-	-	3	V		
	Reverse current	I _R	V _R = 4V	-	-	10	μA		
	Terminal capacitance	C _t	V = 0, f = 1kHz	-	30	250	pF		
Output	Collector dark current	I _{CEO}	V _{CE} = 200V, I _F = 0, R _{BE} = ∞	-	-	10 ⁻⁶	A		
	Current transfer ratio	CTR	I _F = 1mA, V _{CE} = 2V, R _{BE} = ∞	1 000	4 000	15 000	%		
Transfer characteristics	Collector-emitter saturation voltage	V _{CE(sat)}	I _F = 20mA, I _C = 100mA, R _{BE} = ∞	-	-	1.2	V		
	Isolation resistance	R _{ISO}	DC500V, 40 to 60% RH	5 x 10 ¹⁰	10 ¹¹	-	Ω		
	Floating capacitance	C _f	V = 0, f = 1MHz	-	0.6	1.0	pF		
	Cut-off frequency	Response time	Rise time	t _r	V _{CE} = 2V, I _C = 20mA	-	100	300	μs
			Fall time	t _f	R _L = 100Ω, R _{BE} = ∞	-	20	100	μs

Fig. 1 Forward Current vs. Ambient Temperature

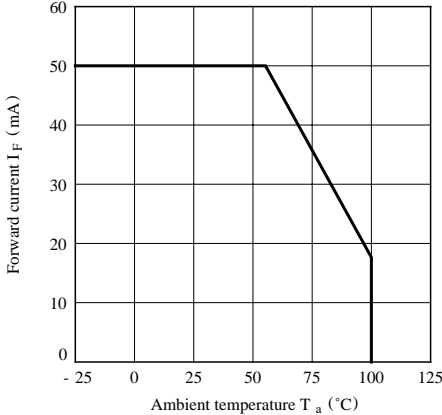


Fig. 2 Collector Power Dissipation vs. Ambient Temperature

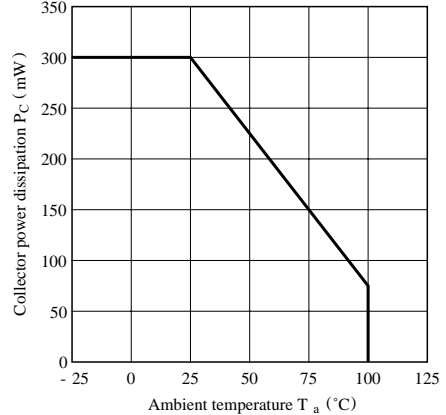


Fig. 3 Peak Forward Current vs. Duty Ratio

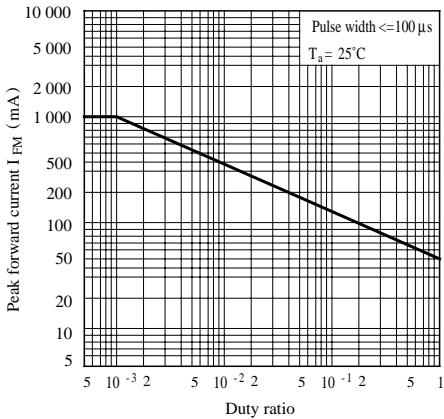


Fig. 4 Forward Current vs. Forward Voltage

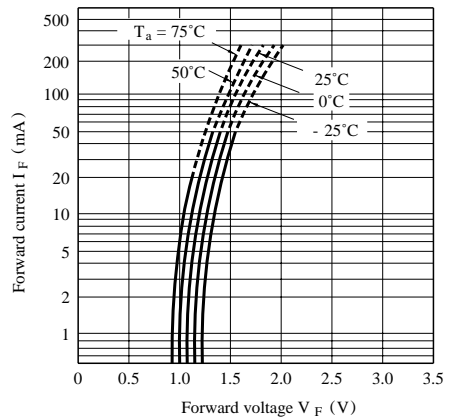


Fig. 5 Current Transfer Ratio vs. Forward Current

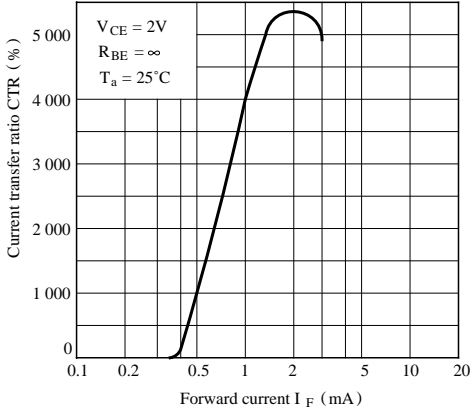


Fig. 6 Collector Current vs. Collector-emitter Voltage

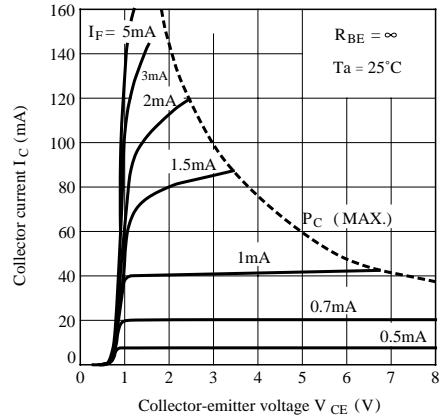


Fig. 7 Relative Current Transfer Ratio vs. Ambient Temperature

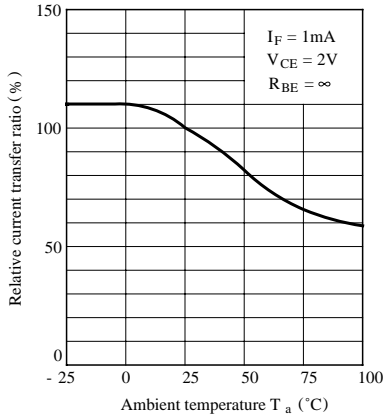


Fig. 8 Collector-emitter Saturation Voltage vs. Ambient Temperature

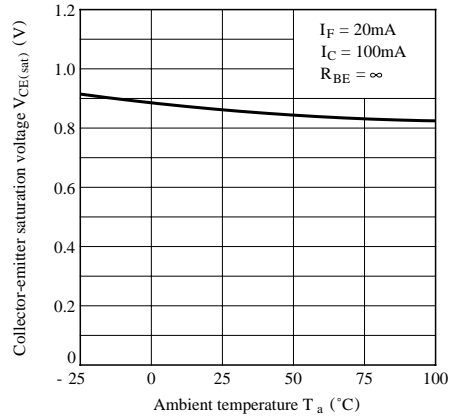


Fig. 9 Collector Dark Current vs. Ambient Temperature

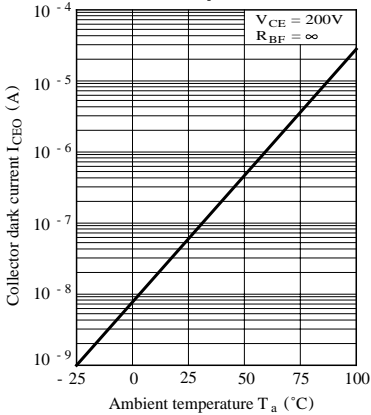
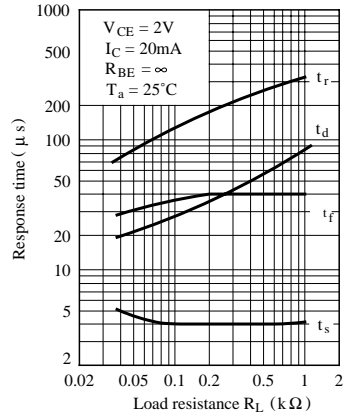


Fig.10 Response Time vs. Load Resistance



Test Circuit for Response Time

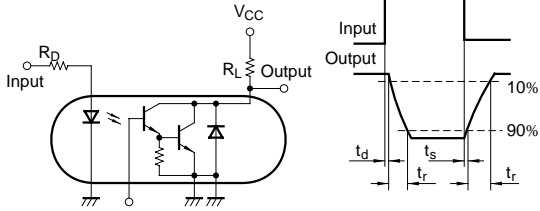
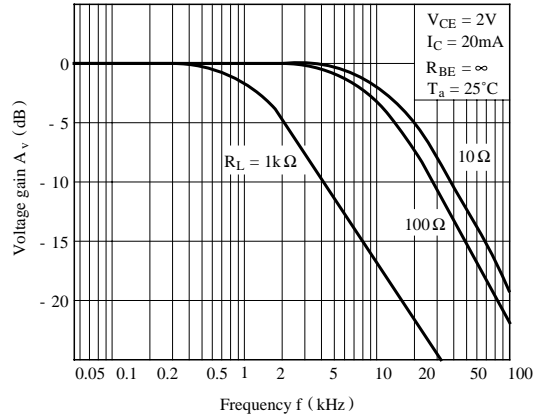
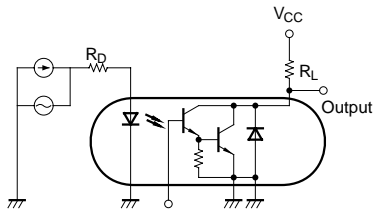


Fig.10 Frequency Response



Test Circuit for Frequency Response



● Please refer to the chapter “Precautions for Use”.